
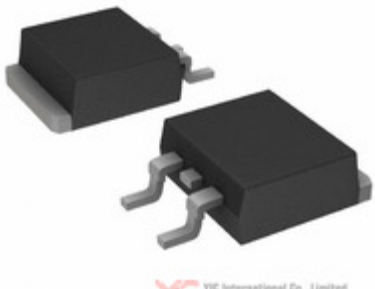
	<p><b>SUD50N04-8M8P-4GE3</b></p>
	<p><b>Hersteller-Teilenummer:</b> SUD50N04-8M8P-4GE3</p> <p><b>Hersteller / Marke:</b> Electro-Films (EFI) / Vishay</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 40V 14A TO-252</p> <p><b>Datenblätter:</b>  <a href="#">SUD50N04-8M8P-4GE3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 32030 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	SUD50N04-8M8P-4GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 40V 14A TO-252
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	32030 pcs Stock
detaillierte Beschreibung	N-Channel 40V 14A (Ta), 50A (Tc) 3.1W (Ta), 48.1W
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252, (D-Pak)
Verlustleistung (max)	3.1W (Ta), 48.1W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	14A (Ta), 50A (Tc)
Rds On (Max) @ Id, Vgs	8.8 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	56nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2400pF @ 20V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SUD50N04-8M8P-4GE3TR

SUD50N04-8M8P-4GE3 ist neu im Original, Suche SUD50N04-8M8P-4GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SUD50N04-8M8P-4GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SUD50N04-8M8P-4GE3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SUD50N06-07L-E3</b> Vishay / Siliconix MOSFET N-CH 60V 96A TO252</p>	 <p><b>SUD50N06-07L-E3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 60V 96A TO252</p>	 <p><b>SUD50N04-37P-T4-GE3</b> VB SUD50N04-37P-T4-GE3 VB</p>	 <p><b>SUD50N04-8M8P-E3</b> V SUD50N04-8M8P-E3 V</p>
 <p><b>SUD50N04-37P-T4-E3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 40V 5.4A TO252</p>	 <p><b>SUD50N06-07L</b> VISHAY SUD50N06-07L VISHAY</p>	 <p><b>SUD50N04-37P-T4-E3</b> Vishay / Siliconix MOSFET N-CH 40V 5.4A TO252</p>	 <p><b>SUD50N06</b> INF INF TO-252</p>

### heiße Teile

Mehr

⊛ SUD50N03-7M3P	↔ SUD50N03A	⇒ SUD50N04-05L	D SUD50N04-05L-E3	⇒ SUD50N04-05L-E3
⊣ SUD50N04-06H	⊛ SUD50N04-06P	D SUD50N04-07	⇒ SUD50N04-07-T4-GE3	⇒ SUD50N04-07L
⊛ SUD50N04-07L-E3	⊣ SUD50N04-09H	⊛ SUD50N04-09H-E3	↔ SUD50N04-09H-E3	⇒ SUD50N04-09L-E3
D SUD50N04-10P-E3	⊛ SUD50N04-13P	⊣ SUD50N04-13P-E3	⊛ SUD50N04-16P	⇒ SUD50N04-25P
⇒ SUD50N04-37P	↔ SUD50N04-37P-E3	⊛ SUD50N04-37P-E3-4GE3	⊣ SUD50N04-37P-T4-GE3	⇒ SUD50N04-8M8P
↔ SUD50N04-8M8P-4GE3	⇒ SUD50N04-8M8P-E3	D SUD50N06-07L	⊛ SUD50N06-07L-GE3	⊣ SUD50N06-07L-GE3
⊛ SUD50N06-08H	D SUD50N06-09L	⇒ SUD50N06-09L-E3	↔ SUD50N06-09L-E3	⇒ SUD50N06-16
⊣ SUD50N06-36	⊛ SUD50N06L-09	↔ SUD50N10-18P	⇒ SUD50N10-18P-E3	⇒ SUD50N10-18P-E3
⊛ SUD50N10-18P-T4-E3	⊣ SUD50N10-34P	⊛ SUD50NP04-62-4-E3	D SUD50NP04-62-T4-E3	⇒ SUD50NP04-77P
↔ SUD50P04-08	⊛ SUD50P04-08-GE3	⊣ SUD50P04-08-GE3	⊛ SUD50P04-08L	⇒ SUD50P04-09L

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited